# 10 GB/s 10Km SFP+ 1310 nm Transceivers



#### Features

- Link lengths at 10G 10Km with DFB 1310nm
- LC duplex connector
- Low power consumption <1.0W</li>
- 0°C to 70°C operating temperature range
- Single +3.3V±5% power supply
- Digital Monitoring SFF-8472 compliant

## **Applications**

- 10GBASE-LR/LW 10G Ethernet
- 10GFC
- 8GFC

### Standards

- IEEE 802.3ae
- SFF-8431 Rev 3.0
- SFF-8472 Rev 10.2
- 10GFC Rev 4.0
- FC-PI-4 Rev 7.0

The RTXM228-401 10Gigabit 1310nm DFB Transceiver is designed to transmit and receive serial optical data links up from 8.5 Gb/s to 10.52 Gb/s data rate over 10km singlemode fiber. The Transceiver is compliant with SFF-8432, 10GFC, FC-PI-4, IEEE802.3ae and applicable portions of SFF-8431. Digital diagnostics functions are available via a 2-wire serial interface, as specified in SFF-8472.

## Specifications

(tested under recommended operating conditions, unless otherwise noted)

Parameter	Symbol	Unit	Min	Тур	Max	Note
Transmitter						
Nominal Wavelength	λ	nm	1260	1310	1360	
Side Mode Suppression Ratio	SMSR	dB	30			
Optical Modulation	POMA	dBm	-5.4			
Amplitude						
Optical Output Power	Pav	dBm	-8.2		0.5	
Extinction Ratio	ER	dB	3.5			
Transmitter and Dispersion	TDP	dB			3.2	
Penalty						
Average launch power of	$P_{OFF}$	dBm			-35	
OFF transmitter						
Relative Intensity Noise	R <sub>IN</sub>	dB/Hz			-128	
Optical Return Loss		dB			12	
Tolerance	ONLI	uр			12	
Output optical eye	Complies with IEEE802.3ae eye masks with filter					
Receiver						
Center Wavelength	λ	nm	1260		1610	
Average Receiver Power	P <sub>AVG</sub>	dBm	-14.4		+0.5	1
Receiver Sensitivity (OMA)	R <sub>SENSE1</sub>	dBm			-12.6	1
Stressed Receiver Sensitivity	R <sub>SENSE2</sub>	dBm		_10	-10.3	2 2
(OMA)					-10.5	2
Receiver Reflectance	R <sub>REFL</sub>	dB			-12	
Assert LOS	LOSA	dBm	-30			
De-Assert LOS	LOSD	dBm			-17	
LOS Hysteresis		dB	0.5			

Note 1: Sensitivity for 10G PRBS 2<sup>31</sup>-1 and BER better than or

equal to 10E-12

**Note 2**: The stressed sensitivity value in the table are for system level BER measurements which include the effects of CDR circuit.